N *ational* *Semiconductor*

LM6164/LM6264/LM6364
High Speed Operational Amplifier

General Description

The LM6164 family of high-speed amplifiers exhibits an excellent speed-power product in delivering 300V per μs and 175 MHz GBW (stable down to gains as low as +5) with only 5 mA of supply current. Further power savings and application convenience are possible by taking advantage of the wide dynamic range in operating supply voltage which extends all the way down to +5V.

These amplifiers are built with National's VIP™ (Vertically Integrated PNP) process which produces fast PNP transistors that are true complements to the already fast NPN devices. This advanced junction-isolated process delivers high speed performance without the need for complex and expensive dielectric isolation.
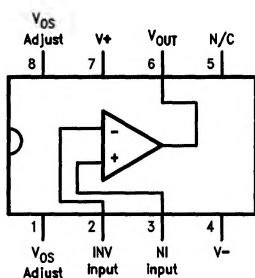
Features

- High slew rate   300 V/μs
- High GBW product   175 MHz
- Low supply current   5 mA
- Fast settling   100 ns to 0.1%
- Low differential gain   <0.1%
- Low differential phase   <0.1°
- Wide supply range   4.75V to 32V
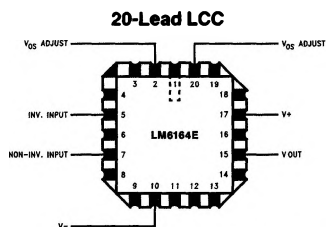- Stable with unlimited capacitive load

Applications

- Video amplifier
- Wide-bandwidth signal conditioning
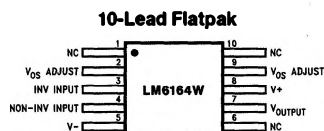- Radar
- Sonar

Connection Diagrams

TL/H/9153–8

**NS Package Number
J08A, M08A or N08E**

20-Lead LCC

TL/H/9153–14

Top View
NS Package Number E20A

10-Lead Flatpak

TL/H/9153–15

Top View
NS Package Number W10A

Temperature Range			Package	NSC Drawing
Military $-55°C \leq T_A \leq +125°C$	**Industrial** $-25°C \leq T_A \leq +85°C$	**Commercial** $0°C \leq T_A \leq +70°C$		
	LM6264N	LM6364N	8-Pin Molded DIP	N08E
LM6164J/883 5962-8962401PA			8-Pin Ceramic DIP	J08A
		LM6364M	8-Pin Molded Surface Mt.	M08A
LM6164E/883 5962-89624012A			20-Lead LCC	E20A
LM6164W/883 5962-8962401HA			10-Pin Ceramic Flatpak	W10A

Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage $(V^+ - V^-)$	36V
Differential Input Voltage (Note 6)	±8V
Common-Mode Input Voltage (Note 10)	$(V^+ - 0.7V)$ to $(V^- - 7V)$
Output Short Circuit to Gnd (Note 1)	Continuous

Soldering Information
  Dual-In-Line Package (N, J)
    Soldering (10 sec.)   260°C
  Small Outline Package (M)
    Vapor Phase (60 sec.)   215°C
    Infrared (15 sec.)   220°C

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

Storage Temperature Range	−65°C to +150°C
Max Junction Temperature (Note 2)	150°C
ESD Tolerance (Notes 6 & 7)	±700V

Operating Ratings

Temperature Range (Note 2)

LM6164	$-55°C \leq T_J \leq +125°C$
LM6264	$-25°C \leq T_J \leq +85°C$
LM6364	$0°C \leq T_J \leq +70°C$
Supply Voltage Range	4.75V to 32V

DC Electrical Characteristics
The following specifications apply for Supply Voltage = ±15V, $V_{CM} = 0$, $R_L \geq 100$ kΩ and $R_S = 50Ω$ unless otherwise noted. **Boldface** limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX}; all other limits $T_A = T_J = 25°C$.

Symbol	Parameter	Conditions	Typ	LM6164 Limit (Notes 3, 11)	LM6264 Limit (Note 3)	LM6364 Limit (Note 3)	Units
V_{OS}	Input Offset Voltage		2	4 **6**	4 **6**	9 **11**	mV max
V_{OS} Drift	Input Offset Voltage Average Drift		6				μV/°C
I_b	Input Bias Current		2.5	3 **6**	3 **5**	5 **6**	μA max
I_{OS}	Input Offset Current		150	350 **800**	350 **600**	1500 **1900**	mA max
I_{OS} Drift	Input Offset Current Average Drift		0.3				nA/°C
R_{IN}	Input Resistance	Differential	100				kΩ
C_{IN}	Input Capacitance		3.0				pF
A_{VOL}	Large Signal Voltage Gain	$V_{OUT} = \pm 10V$, $R_L = 2$ kΩ (Note 9)	2.5	1.8 **0.9**	1.8 **1.2**	1.3 **1.1**	V/mV min
		$R_L = 10$ kΩ	9				
V_{CM}	Input Common-Mode Voltage Range	Supply = ±15V	+14.0	+13.9 **+13.8**	+13.9 **+13.8**	+13.8 **+13.7**	V min
			−13.5	−13.3 **−13.1**	−13.3 **−13.1**	−13.2 **−13.1**	V min
		Supply = +5V (Note 4)	4.0	3.9 **3.8**	3.9 **3.8**	3.8 **3.7**	V min
			1.5	1.7 **1.9**	1.7 **1.9**	1.8 **1.9**	V max
CMRR	Common-Mode Rejection Ratio	$-10V \leq V_{CM} \leq +10V$	105	86 **80**	86 **82**	80 **78**	dB min
PSRR	Power Supply Rejection Ratio	$\pm 10V \leq V\pm \leq \pm 16V$	96	86 **80**	86 **82**	80 **78**	dB min

DC Electrical Characteristics

The following specifications apply for Supply Voltage = ±15V, V_{CM} = 0, $R_L \geq$ 100 kΩ and R_S = 50Ω unless otherwise noted. **Boldface** limits apply for $T_A = T_J = T_{MIN}$ to T_{MAX}; all other limits $T_A = T_J$ = 25°C. (Continued)

Symbol	Parameter	Conditions	Typ	LM6164 Limit (Notes 3, 11)	LM6264 Limit (Note 3)	LM6364 Limit (Note 3)	Units
V_O	Output Voltage Swing	Supply = +5V and R_L = 2 kΩ	+14.2	+13.5 **+13.3**	+13.5 **+13.3**	+13.4 **+13.3**	V min
			−13.4	−13.0 **−12.7**	−13.0 **−12.8**	−12.9 **−12.8**	V min
		Supply = +5V and R_L = 2 kΩ (Note 9)	4.2	3.5 **3.3**	3.5 **3.3**	3.4 **3.3**	V min
			1.3	1.7 **2.0**	1.7 **1.9**	1.8 **1.9**	V max
	Output Short Circuit Current	Source	65	30 **20**	30 **25**	30 **25**	mA min
		Sink	65	30 **20**	30 **25**	30 **25**	mA min
I_S	Supply Current		5.0	6.5 **6.8**	6.5 **6.7**	6.8 **6.9**	mA min

AC Electrical Characteristics

The following specifications apply for Supply Voltage = ±15V, V_{CM} = 0, R_L ≥ 100 kΩ and R_S = 50Ω unless otherwise noted. **Boldface** limits apply for T_A = T_J = T_{MIN} to T_{MAX}; all other limits T_A = T_J = 25°C.

Symbol	Parameter	Conditions	Typ	LM6164 Limit (Notes 3, 11)	LM6264 Limit (Note 3)	LM6364 Limit (Note 3)	Units
GBW	Gain-Bandwidth Product	F = 20 MHz	175	140 **100**	140 **120**	120 **100**	MHz min
		Supply = ±5V	120				
SR	Slew Rate	A_V = +5 (Note 8)	300	200 **180**	200 **180**	200 **180**	V/μs min
		Supply = ±5V	200				
PBW	Power Bandwidth	V_{OUT} = 20 V_{PP}	4.5				MHz
T_S	Settling Time	10V Step to 0.1% A_V = −4, R_L = 2 kΩ	100				ns
ϕ_m	Phase Margin	A_V = +5	45				Deg
A_D	Differential Gain	NTSC, A_V = +10	<0.1				%
ϕ_D	Differential Phase	NTSC, A_V = +10	<0.1				Deg
e_{np-p}	Input Noise Voltage	F = 10 kHz	8				nV/$\sqrt{Hz}$
i_{np-p}	Input Noise Current	F = 10 kHz	1.5				pA/$\sqrt{Hz}$

Note 1: Continuous short-circuit operation at elevated ambient temperature can result in exceeding the maximum allowed junction temperature of 150°C.

Note 2: The typical junction-to-ambient thermal resistance of the molded plastic DIP (N) is 105°C/Watt, the molded plastic SO (M) package is 155°C/Watt, and the cerdip (J) package is 125°C/Watt. All numbers apply for packages soldered directly into a printed circuit board.

Note 3: Limits are guaranteed by testing or correlation.

Note 4: For single supply operation, the following conditions apply: V+ = 5V, V− = 0V, V_{CM} = 2.5V, V_{OUT} = 2.5V. Pin 1 & Pin 8 (V_{OS} Adjust) are each connected to Pin 4 (V−) to realize maximum output swing. This connection will degrade V_{OS}.

Note 5: C_L ≤ 5 pF.

Note 6: In order to achieve optimum AC performance, the input stage was designed without protective clamps. Exceeding the maximum differential input voltage results in reverse breakdown of the base-emitter junction of one of the input transistors and probable degradation of the input parameters (especially V_{OS}, I_{OS}, and Noise).

Note 7: The average voltage that the weakest pin combinations (those involving Pin 2 or Pin 3) can withstand and still conform to the datasheet limits. The test circuit used consists of the human body model of 100 pF in series with 1500Ω.
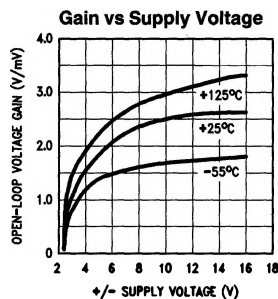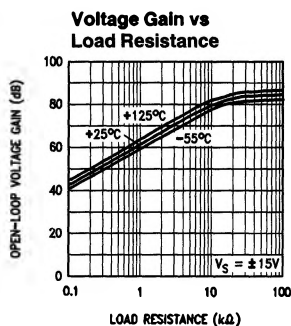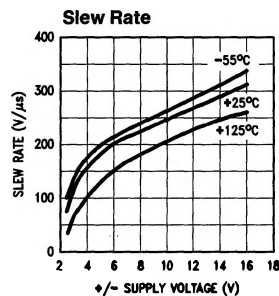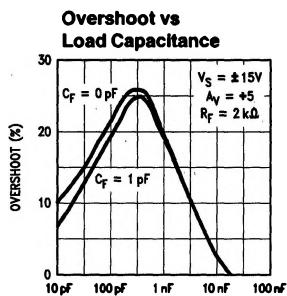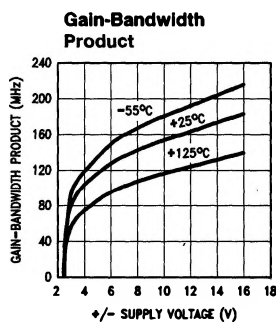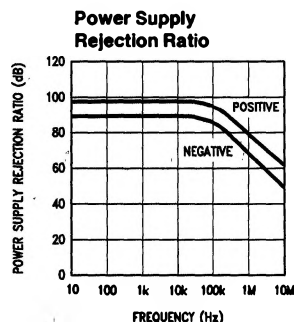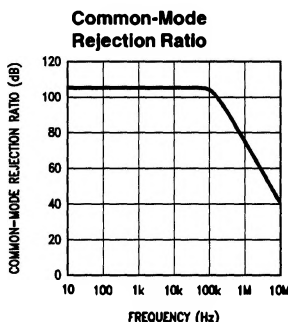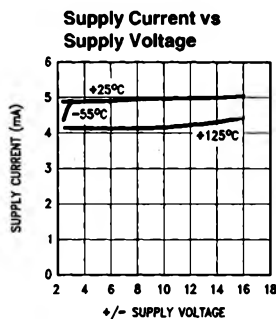
Note 8: V_{IN} = 4V step. For supply = ±5V, V_{IN} = 1V step.

Note 9: Voltage Gain is the total output swing (20V) divided by the input signal required to produce that swing.

Note 10: The voltage between V+ and either input pin must not exceed 36V.

Note 11: A military RETS electrical test specification is available on request. At the time of printing, the LM6164J/883 RETS spec complied with the **Boldface** limits in this column. The LM6164J/883 may also be procured as Standard Military Drawing #5962-8962401PA.

Typical Performance Characteristics (R_L = 10 kΩ, T_A = 25°C unless otherwise specified)

Supply Current vs Supply Voltage

Common-Mode Rejection Ratio

Power Supply Rejection Ratio

Gain-Bandwidth Product

Propagation Delay Rise and Fall Time

Gain-Bandwidth Product vs Load Capacitance

Slew Rate vs Load Capacitance

Overshoot vs Load Capacitance

Slew Rate

Voltage Gain vs Load Resistance

Gain vs Supply Voltage

TL/H/9153–5

1-535

Typical Performance Characteristics

$(R_L = 10\ k\Omega, T_A = 25°C$ unless otherwise specified) (Continued)

Differential Gain (Note)
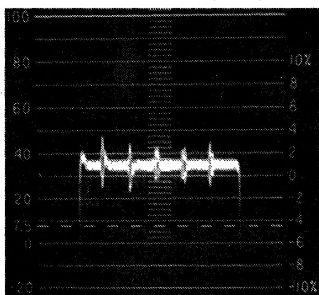
TL/H/9153-6

### Differential Phase (Note)
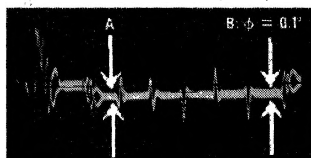
TL/H/9153-7

Note: Differential gain and differential phase measured for four series LM6364 op amps in series with an LM6321 buffer. Error added by LM6321 is negligible. Test performed using Tektronix Type 520 NTSC test system. Configured with a gain of +5 (each output attenuated by 80%)

Step Response; Av = +5

TL/H/9153-1

TIME (50 ns/div)

Input Noise Voltage
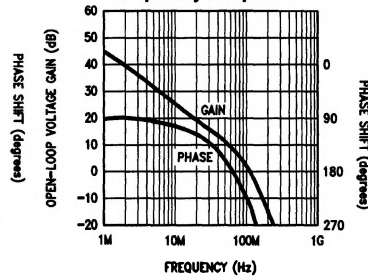

Input Noise Current

Power Bandwidth
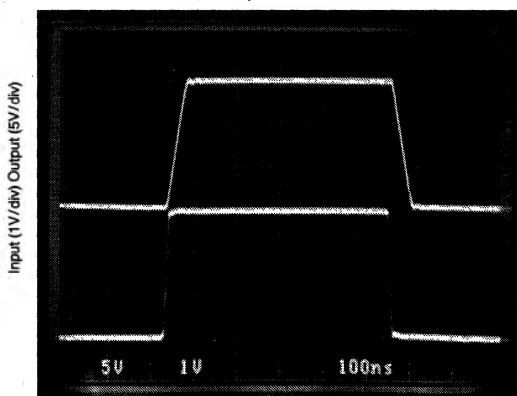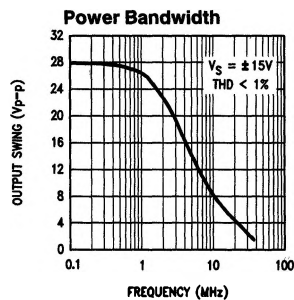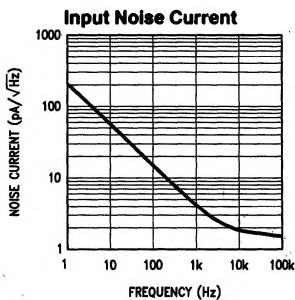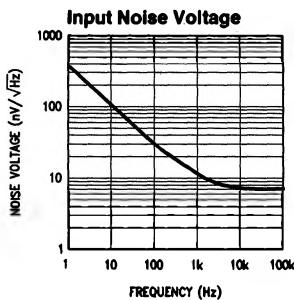
TL/H/9153-9

Typical Performance Characteristics

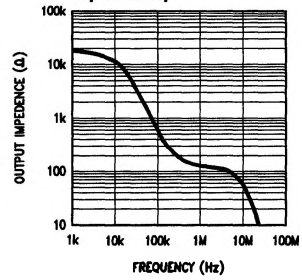(R_L = 10 kΩ, T_A = 25°C unless otherwise specified) (Continued)
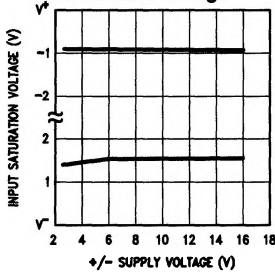
Open-Loop Frequency Response
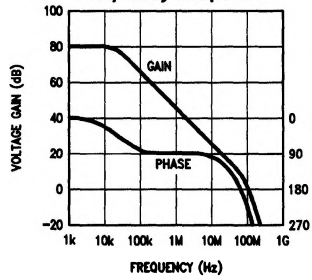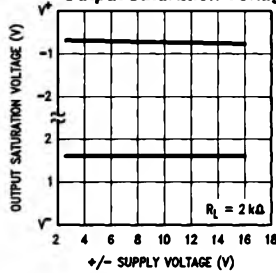
Open-Loop Frequency Response
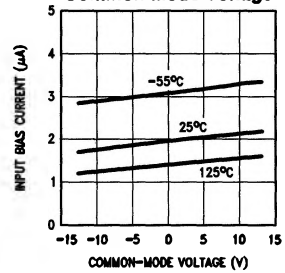
Output Resistance Open-Loop

Common-Mode Input Saturation Voltage

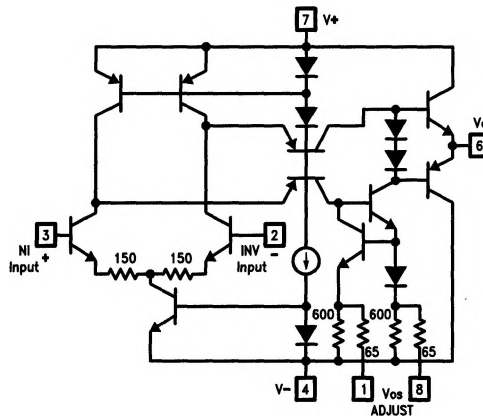### Output Saturation Voltage

Bias Current vs Common-Mode Voltage

TL/H/9153-13

Simplified Schematic

TL/H/9153-3

Applications Tips

The LM6364 has been compensated for gains of 5 or greater (over specified ranges of temperature, power supply voltage, and load). Since this compensation involved adding emitter-degeneration resistors in the op amp's input stage, the open-loop gain was reduced as the stability increased. Gain error due to reduced A_{VOL} is most apparent at high gains; thus, the uncompensated LM6365 is appropriate for gains of 25 or more. If unity-gain operation is desired, the LM6361 should be used. The LM6361, LM6364, and LM6365 have the same high slew rate (typically 300 V/μs), regardless of their compensation.

The LM6364 is unusually tolerant of capacitive loads. Most op amps tend to oscillate when their load capacitance is greater than about 200 pF (in low-gain circuits). However, load capacitance on the LM6364 effectively increases its compensation capacitance, thus slowing the op amp's response and reducing its bandwidth. The compensation is not ideal, though, and ringing or oscillation may occur in low-gain circuits with large capacitive loads. To overcompensate the LM6364 for operation at gains less than 5, a series resistor-capacitor network should be added between the input pins (as shown in the Typical Applications, Noise-Gain Compensation) so that the high-frequency noise gain rises to at least 5.

Power supply bypassing will improve the stability and transient response of the LM6364, and is recommended for every design. 0.01 μF to 0.1 μF ceramic capacitors should be used (from each supply "rail" to ground); if the device is far away from its power supply source, an additional 2.2 μF to 10 μF (tantalum) may be required for extra noise reduction.

Keep all leads short to reduce stray capacitance and lead inductance, and make sure ground paths are low-impedance, especially where heavier currents will be flowing. Stray capacitance in the circuit layout can cause signal coupling between adjacent nodes, so that circuit gain unintentionally varies with frequency.

Breadboarded circuits will work best if they are built using generic PC boards with a good ground plane. If the op amps are used with sockets, as opposed to being soldered into the circuit, the additional input capacitance may degrade circuit performance.
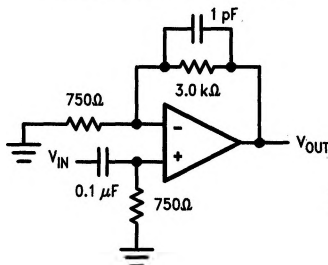
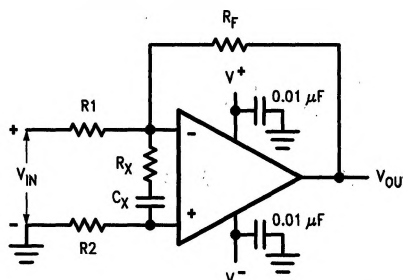## Typical Applications

Offset Voltage Adjustment

TL/H/9153–10

Noise-Gain Compensation for Gains ≤5

TL/H/9153–11
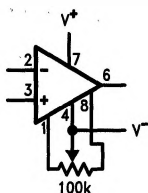
$R_X C_X \geq (2\pi \cdot 25 \text{ MHz})^{-1}$
$5 R_X = R_1 + R_F(1 + R_1/R_2)$

Video-Bandwidth Amplifier

TL/H/9153–12